



BC817-16/-25/-40

**45V NPN SMALL SIGNAL TRANSISTOR IN SOT23** 

#### Features

- Ideally Suited for Automatic Insertion
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (BC807)
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208(3)
- Weight 0.008 grams (approximate)

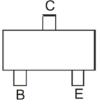


SOT23

Top View

# B-C

**Device Symbol** 



Top View Pin-Out

## Ordering Information (Note 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BC817-16-7-F	AEC-Q101	K6A	7	8	3,000
BC817-25-7-F	AEC-Q101	K6B	7	8	3,000
BC817-25Q-7-F	Automotive	K6B	7	8	3,000
BC817-40-7-F	AEC-Q101	K6C	7	8	3,000
BC817-40Q-7-F	Automotive	K6C	7	8	3,000
BC817-40Q-13-F	Automotive	K6C	13	8	10,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

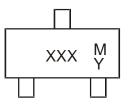
 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



 $\begin{array}{l} XXX = \mbox{Product Type Marking Code (See table above)} \\ YM = \mbox{Date Code Marking} \\ Y = \mbox{Year ex: } X = 2010 \\ M = \mbox{Month ex: } 9 = \mbox{September} \end{array}$ 

Date Code Key

Year	2010	20	011	2012	2	013	2014	2	2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current	Ic	0.5	A
Peak Collector Current	I <sub>CM</sub>	1.0	A
Peak Base Current	I <sub>BM</sub>	200	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	D	310	mW
Power Dissipation	(Note 7)	PD	350	TIVV
Thermal Desistance Junction to Ambient	(Note 6)	D	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R• JA	357	°C/vv
Thermal Resistance, Junction to Leads (Note 8)		R• JL	350	°C/W
Operating and Storage Temperature Range		T <sub>J.</sub> T <sub>STG</sub>	-65 to +150	°C

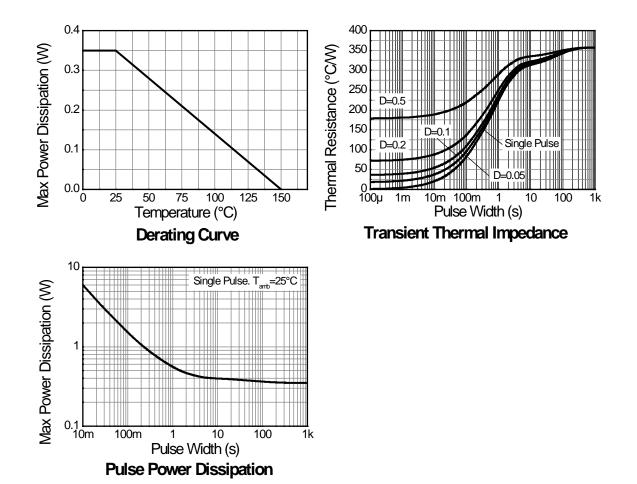
# ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	• 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	• 400	V	С

Notes: 6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; device not the device mounted of minimum recommended pad tayout FR4 FCB with measured when operating in steady state condition.
Same as Note 6, except the device is mounted on 15mm X 15mm FR4 PCB.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



# Thermal Characteristics and Derating Information





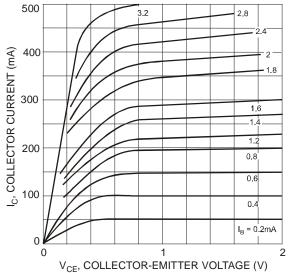
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

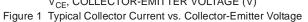
Characteristic			Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	50	_		V	I <sub>C</sub> = 100μA
Collector-Emitter Breakdown Voltage			45	_	_	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	)	BV <sub>EBO</sub>	5	_	_	V	I <sub>C</sub> = 100µA
Collector-Emitter Cutoff Current		ICES	_	_	100 5.0	nΑ μΑ	V <sub>CE</sub> = 45V V <sub>CE</sub> = 25V, T <sub>J</sub> = +150°C
Emitter-Base Cutoff Current		I <sub>EBO</sub>	_	_	100	nA	V <sub>EB</sub> = 5.0V
	BC817-16 BC817-25 BC817-40		100 160 250		250 400 600		V <sub>CE</sub> = 1.0V, I <sub>C</sub> = 100mA
DC Current Gain (Note 10)	BC817-16 BC817-25 BC817-40	hfe hfe	60 100 170	_	_		V <sub>CE</sub> = 1.0V, I <sub>C</sub> = 300mA
Collector-Emitter Saturation Voltage (Note 10)		V <sub>CE(SAT)</sub>	_	_	0.7	V	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA
Base-Emitter Voltage (Note 10)		VBE	_	_	1.2	V	$V_{CE} = 1.0V, I_C = 300mA$
Gain Bandwidth Product		f <sub>T</sub>	100	—	_	MHz	$\label{eq:Vce} \begin{array}{l} V_{CE} = 5.0V, \ I_C = 10 \text{mA}, \\ f = 50 \text{MHz} \end{array}$
Collector-Base Capacitance		Ссво	_	_	12	pF	$V_{CB} = 10V, f = 1.0MHz$

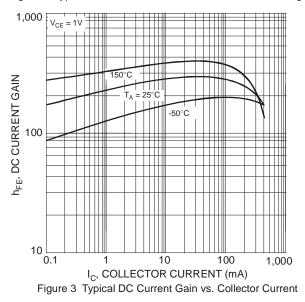
Note: 10. Measured under pulsed conditions. Pulse width • 300µs. Duty cycle • 2%.

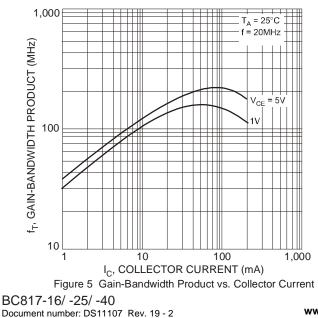


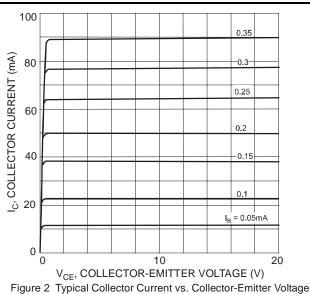
# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

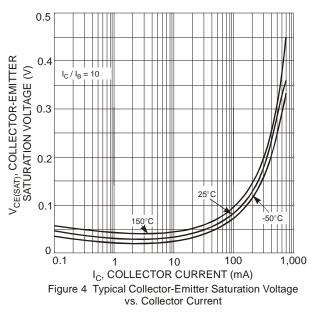








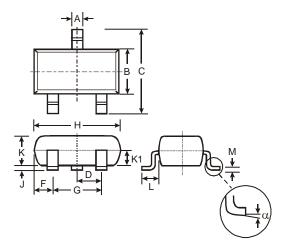






# **Package Outline Dimensions**

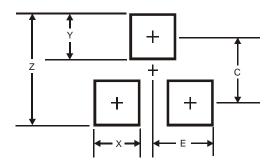
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
κ	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
М	0.085	0.18	0.11			
α	0°	8°	-			
All	Dimens	ions in	mm			

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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